Solid state sources for quantum communications

J. J. H. Eng, X. Lyu, M. Meunier, L. Kallioniemi, L. Ang, H. Zhang, N. Lecaron, Z. Jiang, A. Rasmita, Y. Yang, F. Zhou, H. Cai, S. Chenot, Z. Dong, W. Gao, and J. Zuniga-Perez

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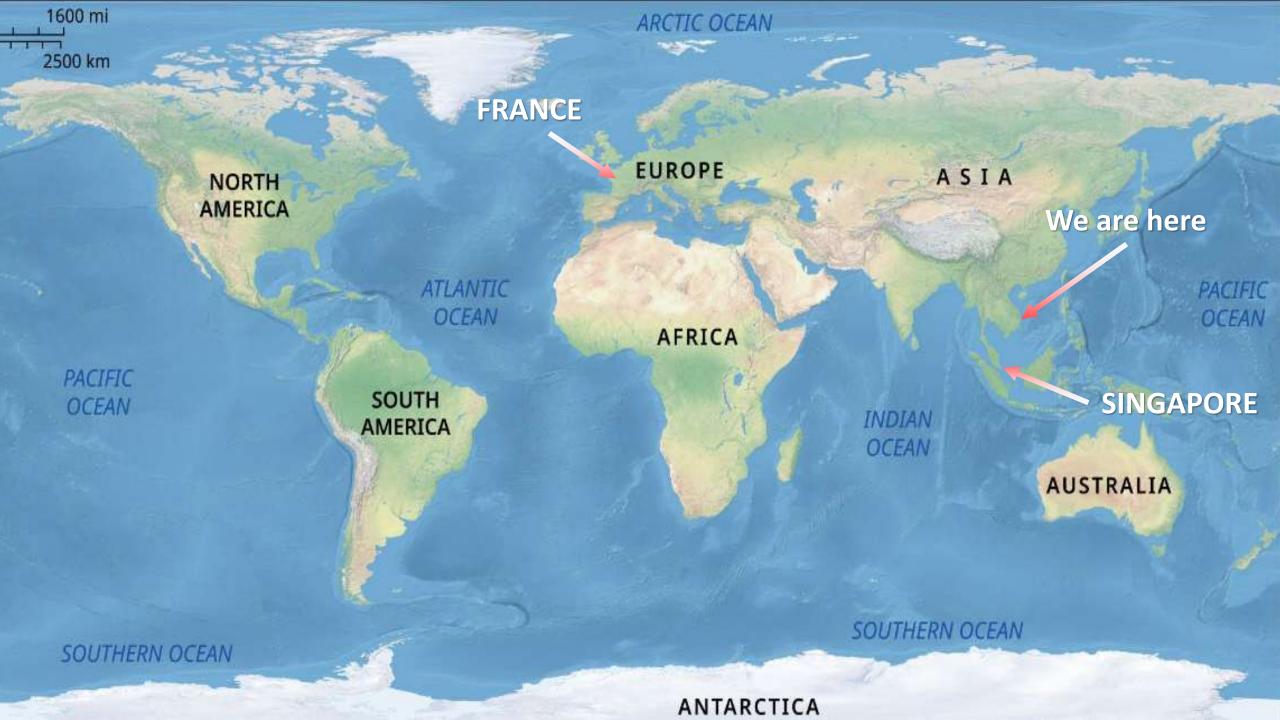


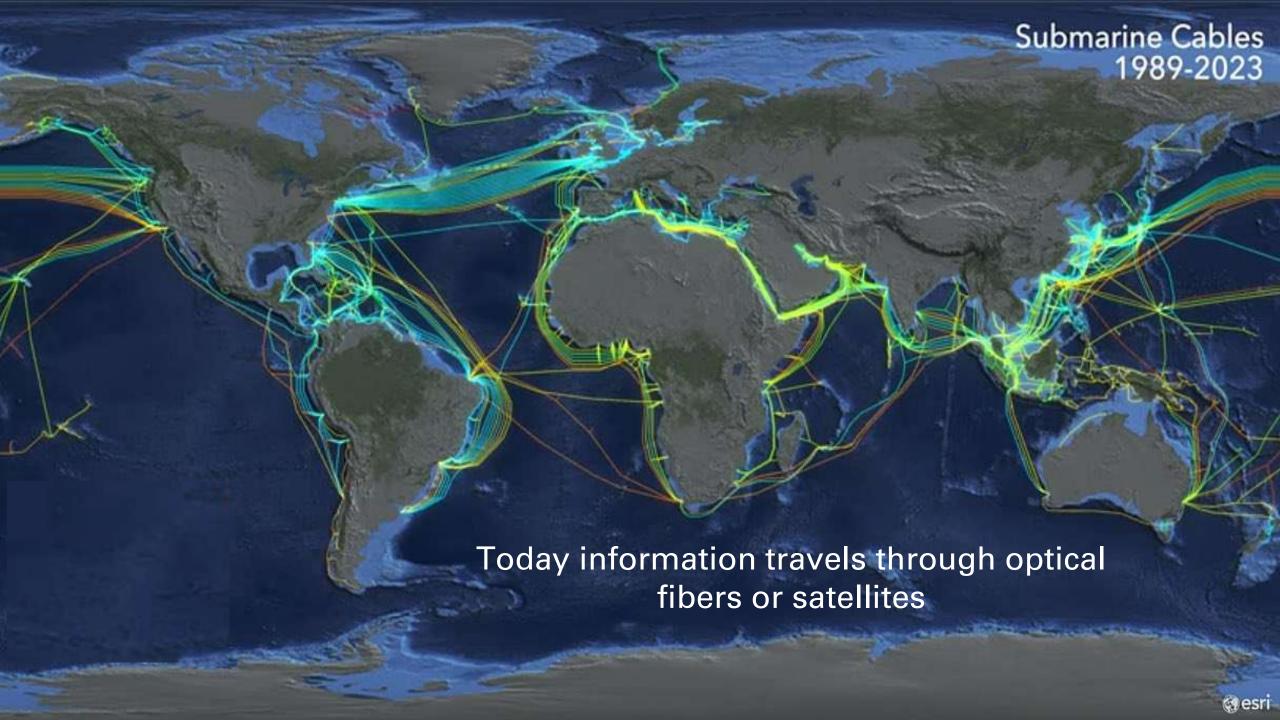










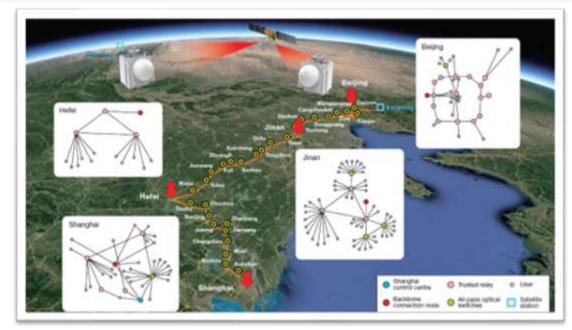


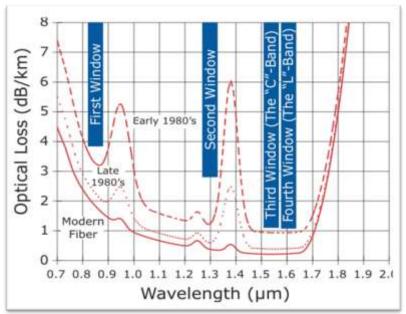
Quantum communications: single-photon emitters at telecomm λ

 Quantum internet will relie on existing infrastructures: satellite-based communications combined with local or regional optical-fiber networks

Y. A. Chen et al., Nature 589 (2021) 214

• Quantum sources emitting at 1.3μm or 1.55μm at room-tempereature would be ideal, specially in terms of integration, although frequency conversion can be extremely efficient.





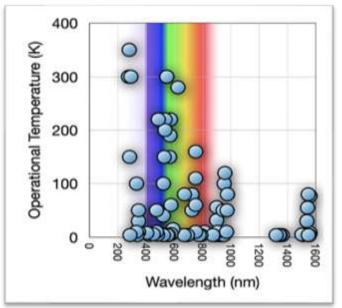
Quantum communications: single-photon emitters at telecomm. λ

 The most performant single-photon emitters are based on epitaxial quantum dots

A. K. Nowak *et al.*, Nature Comm. **5** (2014) 3240 https://www.quandela.com/

- The operation temperature decreases with increasing wavelength: telecom single-photon emitters need cryogenic cooling.
- The purity of the emitter degrades with increasing temperature.





Outline

- Brief Motivation:
 - Quantum communications at 300K
- Colour-centers in GaN: Telecommunication single-photon emitters
 - Coupling single-photon emitters to bulleyes antennas:
 - Nature of the emitters:
 - Why are we interested in determining their nature? Identification
 - Optically detected magnetic resonance.
 - Spin quantization axis
- Entangled photon-pair sources in 2D materials:
 - Bulk nonlinear crystals Vs « Thin » nonlinear crystals
 - Van der Waals NbOCl₂: transferable and broadband entangled photon-pair source
 - Rhombohedral BN: production of entangled-photon pairs in Van der Waals materials









Conclusions

Colour centers in GaN: what are we talking about?

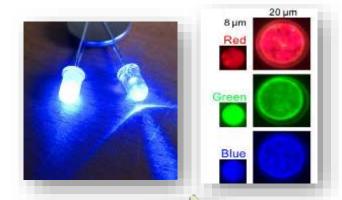
 Colour centers : Point defects in crystals that absorb certain colours





• **GaN**: 2nd semiconductor worldwide

LEDs & lasers



RFs and MWs



Power electronics

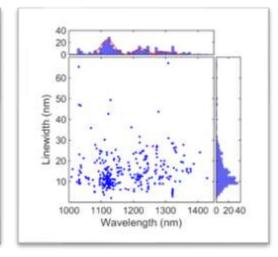
- GaN is widespread and has a mature technology

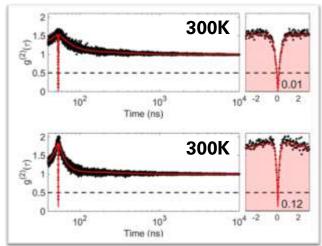


GaN: telecomunication single-photon emitters

 GaN can display colour centers emitting single-photons from 1μm to 1.4μm at 300K Nowalized intensity (a.u.)

Wavelength (nm)

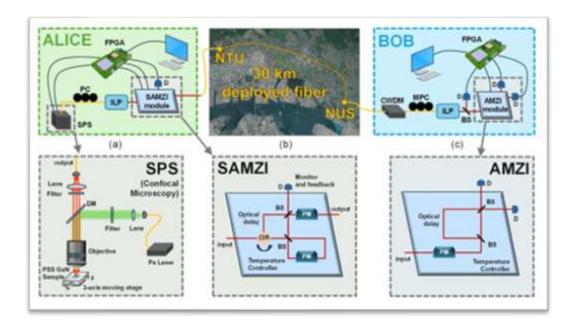


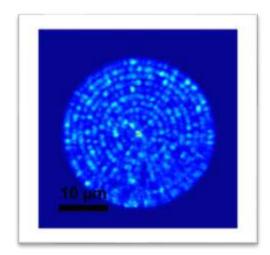


M. Meunier et al., Nanophotonics 12 (2023) 1405-1419

 Thanks to these emitters we have performed a real-field QKD demonstration in the Singaporean quantum network.

H. Zhang et al., Phys. Rev. Appl. 23 (2025) 054022

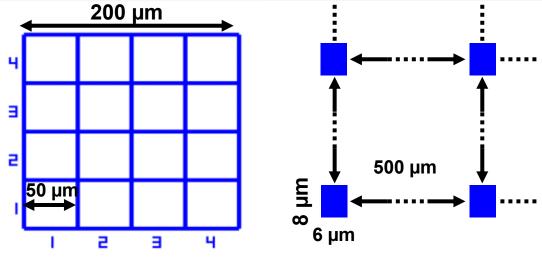




M. Meunier *et al.*, ACS Nano (submitted 2025)

Coupling to photonic structures: spatial alignment

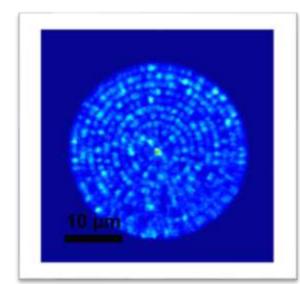
- Today we can not create telecom single-photon emitters in GaN in predefined locations
- To couple them deterministically to photonic structures we need to:
 - 1) Fabricate alignment marks
 - 2) Locate and characterize the emitters
 - 3) Fabricate the photonic structures around them

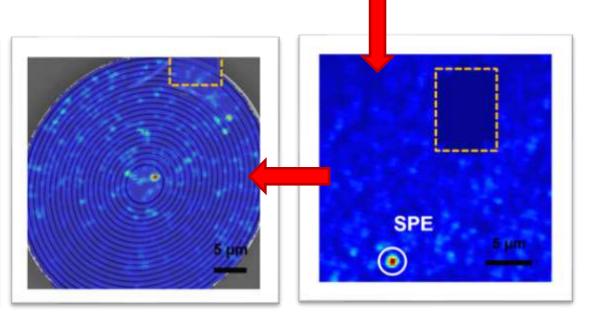


M. Meunier et al., Nanophotonics 12 (2023) 1405-1419

MOTIVATION:

If we knew the nature of the defect, we might produce them deterministically

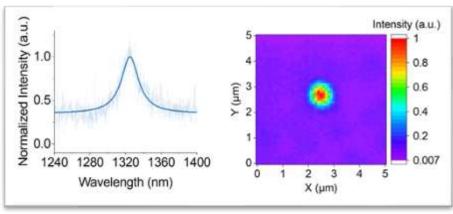


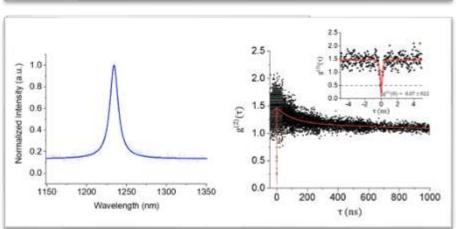


M. Meunier *et al.*, ACS Nano (submitted 2025)

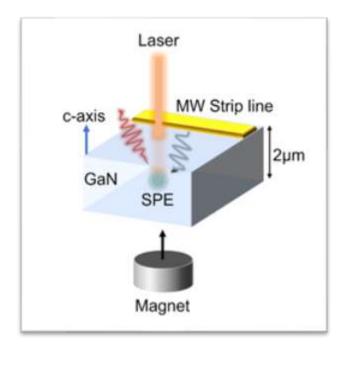
Nature of the emitters: Optically detected magnetic resonance

- Magnetic resonance spectroscopy explores the interaction of electronic (or nuclear) angular momenta with each other and with external magnetic fields
 - We choose a "standard" Oband single-photon emitter

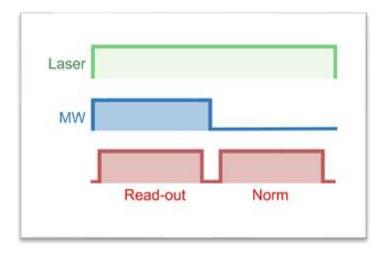




2. We fabricate a MW antenna nearby (+ we apply an external magnetic field)



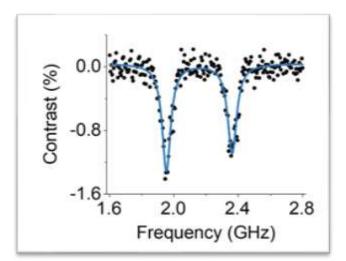
3. We perform the opticallydetected magnetic resonance (ODMR) measurement



$$ODMR\ Contrast = \frac{PL_{read-out} - PL_{norm}}{PL_{read-out} + PL_{norm}}$$

Nature of the emitters: Optically detected magnetic resonance

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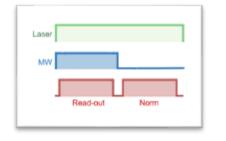


Two distinct transitions

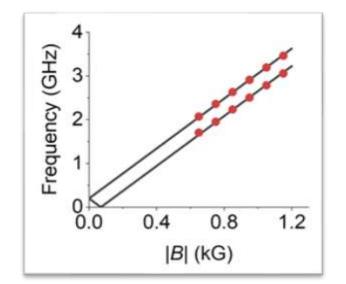


Points to a system with Spin=1

$$H = DS_z^2 + E(S_x^2 - S_y^2) + g\mu_B \vec{B}.\vec{S}$$
$$\left| D \pm \sqrt{E^2 + (\gamma B_z)^2} \right|$$



J. Eng et al., Phys. Rev. Lett. **134** (2025) 083602

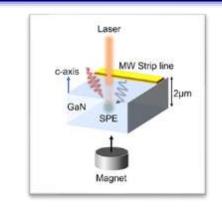


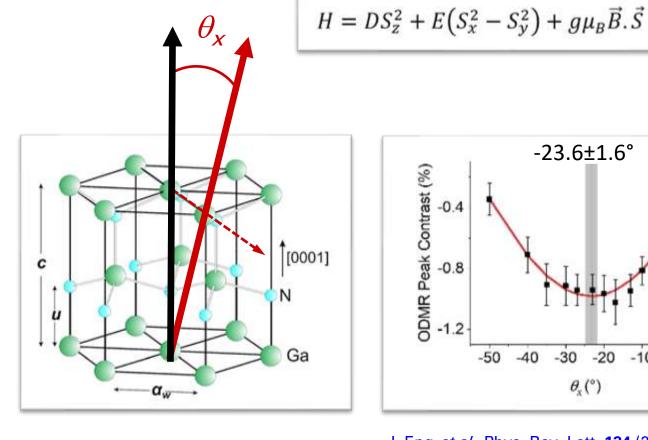
- Linear dependence on the applied magnetic field
- A giromagnetic ratio $\gamma = 28.55 \pm 0.14$ GHz/T

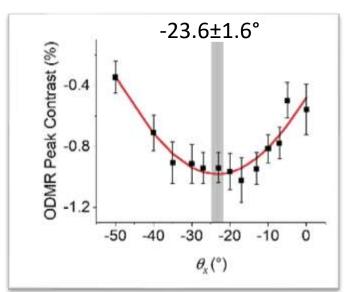
Nature of the emitters: Spin quantization axis

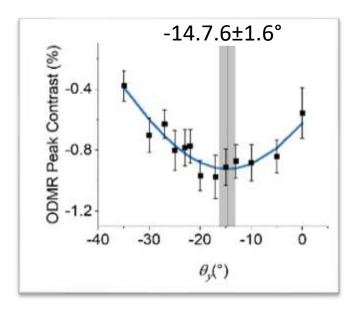
Magnetic resonance spectroscopy explores the interaction of electronic (or nuclear) angular momenta with each other and with external magnetic fields

To determine the direction of the **defect spin quantization axis** we need to measure ODMR as a function of the B-field orientation (for constant field strength)





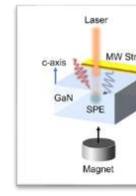


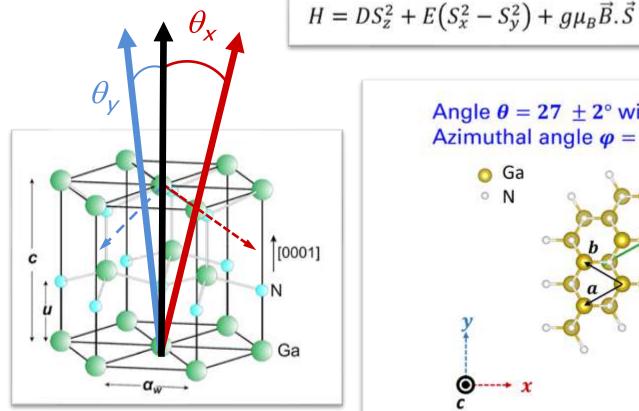


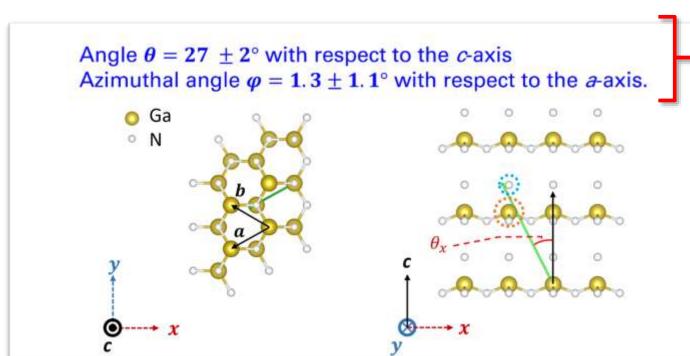
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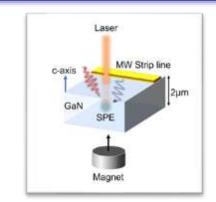


Does not correspond to any lattice vector

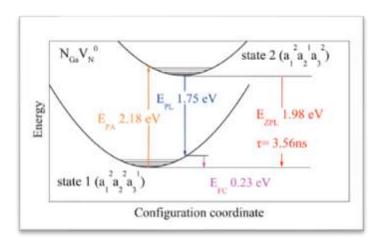
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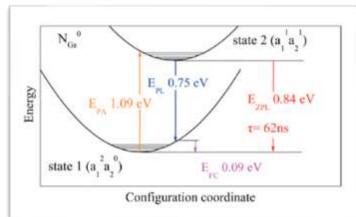
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 $H = DS_z^2 + E(S_x^2 - S_y^2) + g\mu_B \vec{B} \cdot \vec{S}$



We "hope" that by correlating ab-initio calculations on point defects in GaN and our experimental
data (lifetime, spin quantization axis orientation, "energy level diagram",) it will be possible to
assess the exact nature of the defect/s.





Charge	-1	0	+1
Spin	Down	Down	Down
ZPL	0.86 eV (1426 nm)	1.98 eV (625 nm)	0.94 eV (1323 nm)
Transition rates r [s-1]	1.62×10^8	2.81×10^8	5.72×10^6
Lifetime r[ns]	6.19	3.56	175
Transition channel	a ₃ to a ₄	a2 to a3	a2 to a3
Suitable for room temperature SPE	No	Yes	Yes

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Entangled photon-pair sources in 2D materials:

- Bulk nonlinear crystals Vs « Thin » nonlinear crystals
- Van der Waals NbOCl₂: transferable and broadband entangled photon-pair source
- Rhombohedral BN: production of entangled-photon pairs in Van der Waals materials





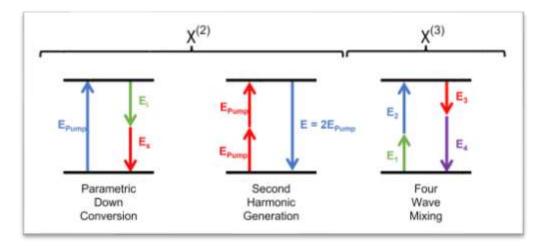




Conclusions

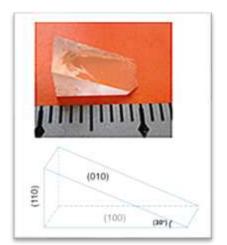
Motivation: issue with entanglement production

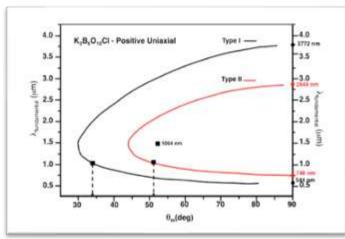
• Entangled photon pair generation: the most widely used process is spontaneous parametric dowconversion (SPDC).

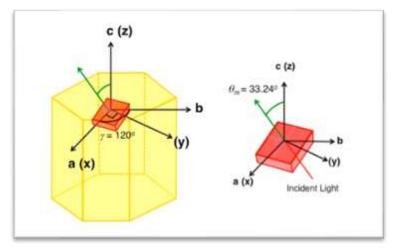


SPDC requires fullfilment of energy-conservation and of momentum-conservation (phase matching conditions)

W. Zhang et al., Chem. Mater. 29 (2017) 2655







MAJOR PROBLEMS: Narrow-band, very rigid design (one crystal=one wavelength), extremely sensitive to optical alignment (i.e. very sensitive to vibrations)

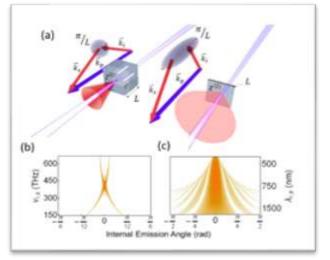
Motivation: issue with entanglement production

 To circumvent phase-matching: nonlinear medium shorter than the coherence length



ADVANTAGES: Broadband and large « angular acceptance »

Potential interest of 2D materials

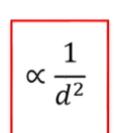


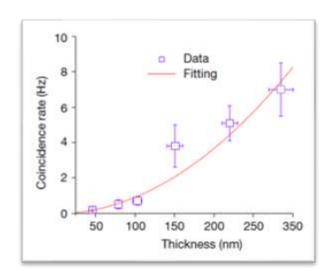


C. Okoth et al. Phys. Rev. Lett. 123, 263602 (2019)

- Issues for nonlinear optics:
- 1) As size shrinks strong reduction of emission rate

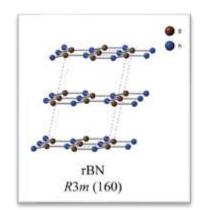
The generation rate squares as

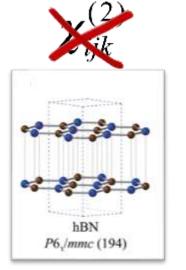




Q. Guo et al., Nature 613, 53 (2023)

2) Many 2D are centrosymetric





Nonlinear optics with r-BN: source of entangled-photons

Intrinsic properties of r-BN:

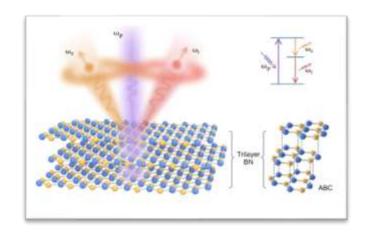
1. Crystal symmetries:

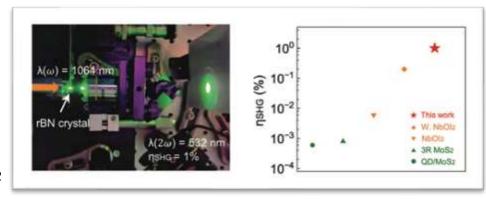
- → Broken out-of-plane inversion symmetry.
- → Preserved in-plane inversion symmetry.

2. Strong nonlinear coefficients:

→ Larger than other nonlinear 2D crystals.

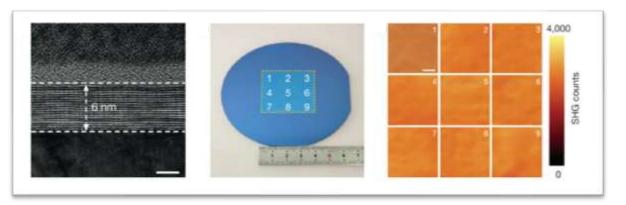
J. Qi et al., Adv. Mater. 36 (2024) 2303122





3. r-BN layers can be grown:

→ Large crystals accessible.

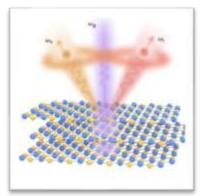


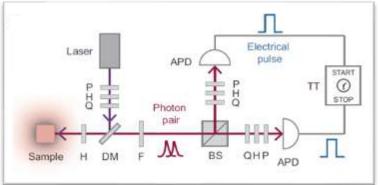
Nonlinear optics with r-BN: measuring/producing entangled-photons

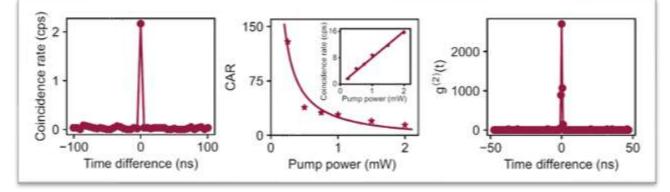
1. Characterization:

X. Lyu *et al.*, Nat. Comm. **16** (2025) 1899

→ Standard **Hanbury Brown-Twiss** setup: biphoton states

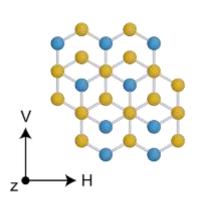




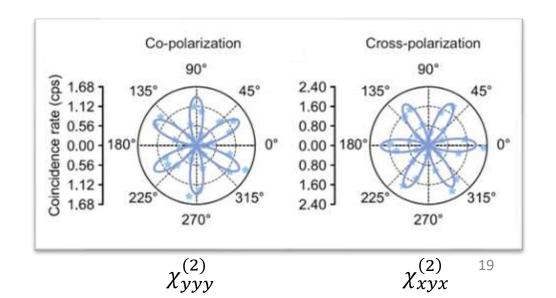


2. Symmetry-based considerations:

→ By changing the pump polarization we can produce different entangled states.



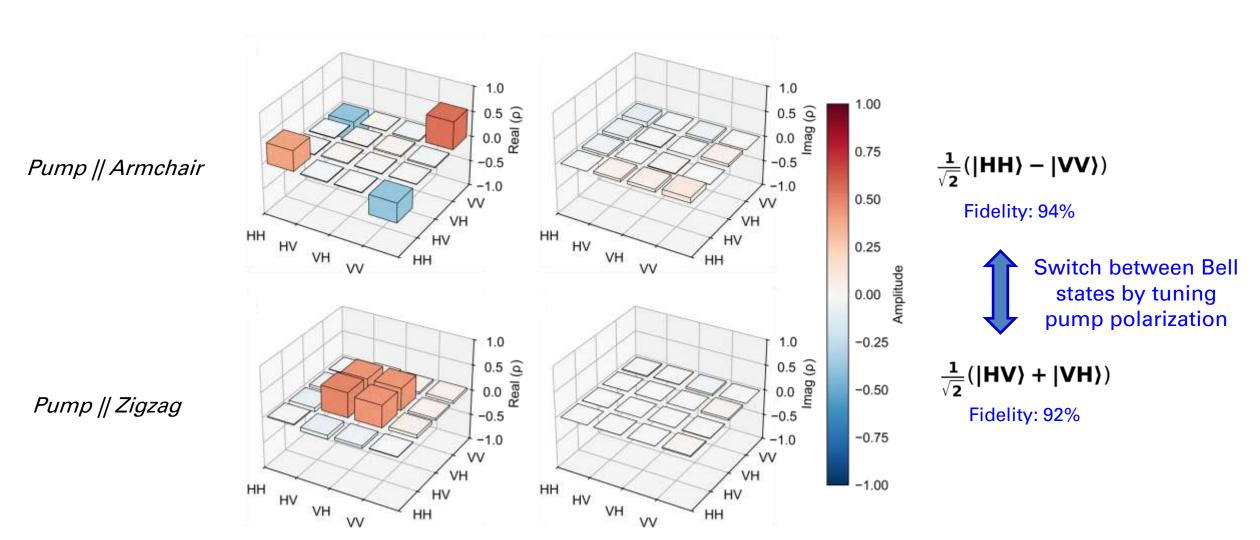
$$\chi_{yyy}^{(2)} = -\chi_{yxx}^{(2)} = -\chi_{xxy}^{(2)} = -\chi_{xyx}^{(2)} = |\chi^{(2)}|$$



Nonlinear optics with r-BN: producing Bell states

3. Quantum tomography of the states produced:

X. Lyu et al., Nat. Comm. 16 (2025) 1899



Conclusions

Colour centers (point-defects) in GaN can operate as bright telecom single-photon emitters



- They appear systematically in certain GaN thin films samples.
- Photonic structures can be processed and enhance their brightness

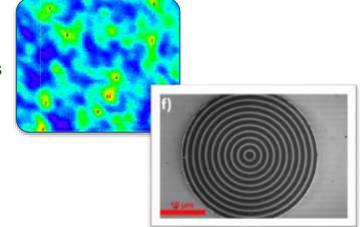


- We can not produce them yet in pre-designed locations
- Upon processing, some emitters are destroyed

M. Meunier *et al.*, Nanophotonics **12** (2023) 1405-1419

H. Zhang *et al.*, Phys. Rev. Appl. **23** (2025) 054022

J. Eng *et al.*, Phys. Rev. Lett. **134** (2025) 083602



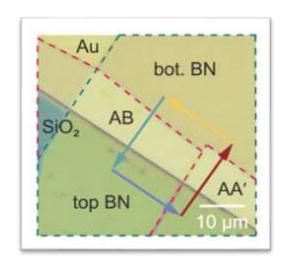
Nonlinear photonics with 2D materials



- Some have intrisinsic large nonlinear coefficients.
- Low-symmetry materials can produce easily different entangled states
- By controlling their thickness they can be made broadband



- The production rate of entangled-photon pairs needs to be enhanced
- Efficient coupling to integrated photonics needs to be demonstrated



Conclusions

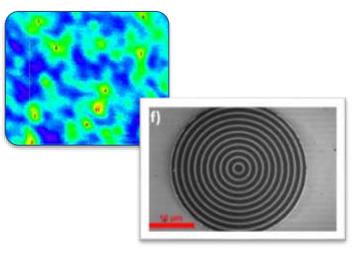
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- Electrical injection
- On-chip integration



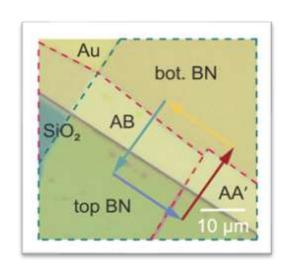
Nonlinear photonics with 2D materials



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- Tuning of entangled states
- Proof-of-concept usercase





Funding agencies









